

M37710M4LXXXFP**SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER****DESCRIPTION**

The M37710M4LXXXFP is a single-chip 16-bit microcomputer designed with high-performance CMOS silicon gate technology. This is housed in a small 80-pin plastic molded QFP.

This microcomputer has a large 16M bytes address space, three instruction queue buffers, and two data buffers for high-speed instruction execution. The CPU is a 16-bit parallel processor that can also be switched to perform 8-bit parallel processing. This microcomputer is suitable for communication, office, business and industrial equipment controller that require high-speed processing of large data. Its strong points are the low supply voltage and the small package.

FEATURES

- Number of basic instructions 103
- Memory size ROM 32K bytes
- RAM 1024 bytes
- Instruction execution time
The fastest instruction at 8MHz frequency 500ns
- Single low supply voltage 2.7~5.5V
- Low power dissipation
(At 3V supply voltage, 8MHz frequency) ... 12mW (Typ.)
(At 5V supply voltage, 8MHz frequency) ... 30mW (Typ.)

- Wide operating temperature range -40~85°C
- Interrupts 19 types 7 levels
- Multiple function 16-bit timer 5+3
(Pulse motor drive waveform can be output)
- UART (may also be synchronous) 2
- 10-bit A-D converter 8-channel inputs
- 8-bit D-A converter 2-channel outputs
- 12-bit watchdog timer
- Programmable input/output
(ports P0, P1, P2, P3, P4, P5, P6, P7, P8) 68

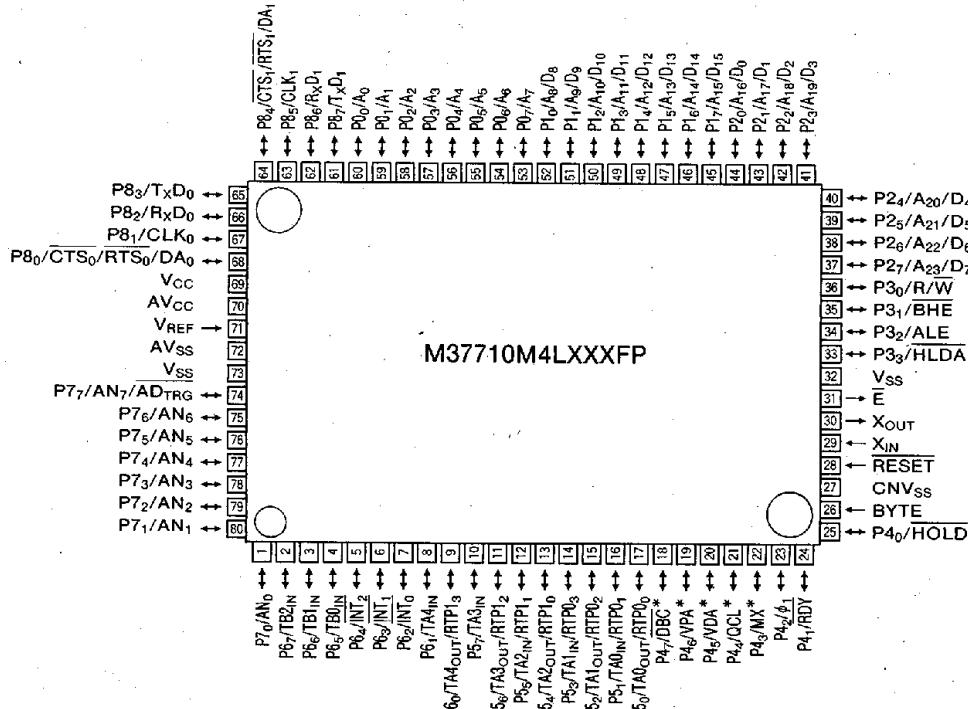
APPLICATION

Control devices for office equipment such as copiers, printers, typewriters, facsimiles, word processors, and personal computers

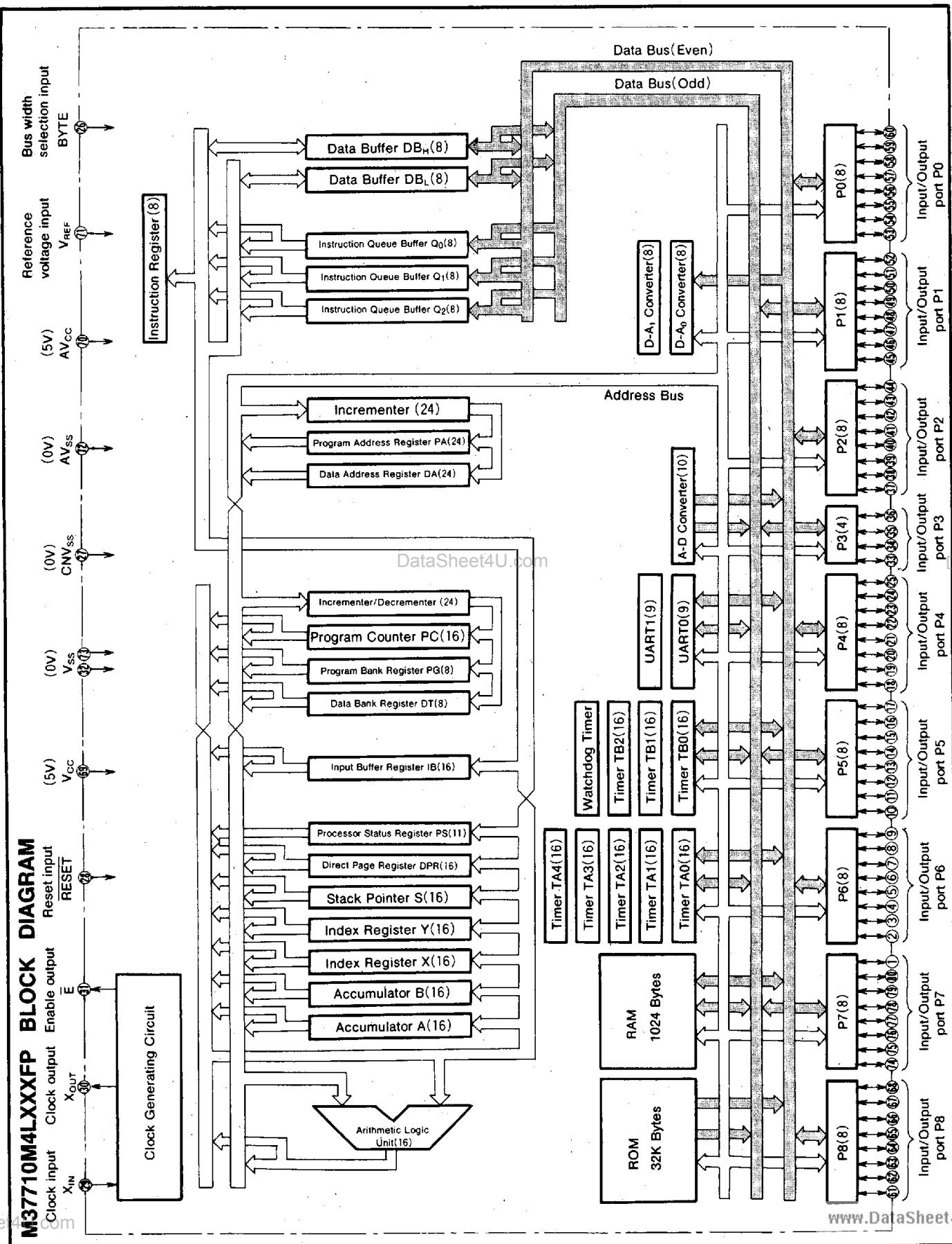
Control devices for industrial equipment such as ME, NC, communication, portable equipment, and measuring instruments

NOTE

Refer to "Chapter 5 PRECAUTIONS" when using this microcomputer.

PIN CONFIGURATION (TOP VIEW)**Outline 80P6N-A**

*: Used in the evaluation chip mode only



SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER**FUNCTIONS OF M37710M4LXXXFP**

Parameter		Functions
Number of basic instructions		103
Instruction execution time		500ns (the fastest instruction at external clock 8MHz, frequency)
Memory size	ROM	32K bytes
	RAM	1024 bytes
Input/Output ports	P0~P2, P4~P8	8-bit×8
	P3	4-bit×1
Multi-function timers	TA0, TA1, TA2, TA3, TA4	16-bit×5
	TB0, TB1, TB2	16-bit×3
Serial I/O		(UART or clock synchronous serial I/O)×2
A-D converter		10-bit×1 (8 channels)
D-A converter		8-bit×2
Watchdog timer		12-bit×1
Interrupts		3 external types, 16 internal types (Each interrupt can be set the priority levels to 0 ~ 7.)
Clock generating circuit		Built-in(externally connected to a ceramic resonator or quartz crystal resonator)
Supply voltage		2.7~5.5V
Power dissipation		12mW (At 3V supply voltage, external clock 8 MHz frequency) 30mW (At 5V supply voltage, external clock 8 MHz frequency)
Input/Output characteristic	Input/Output voltage	5 V
	Output current	5 mA
Memory expansion		Maximum 16M bytes
Operating temperature range		-40~85°C
Device structure		CMOS high-performance silicon gate process
Package		80-pin plastic molded QFP

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER**PIN DESCRIPTION**

Pin	Name	Input/Output	Functions
V _{CC} , V _{SS}	Power supply		Supply 2.7~5.5V to V _{CC} and 0V to V _{SS} .
CNV _{SS}	CNV _{SS} input	Input	This pin controls the processor mode. Connect to V _{SS} for single-chip mode, and to V _{CC} for external ROM types.
RESET	Reset input	Input	To enter the reset state, this pin must be kept at a "L" condition which should be maintained for the required time.
X _{IN}	Clock input	Input	These are I/O pins of internal clock generating circuit. Connect a ceramic or quartz crystal resonator between X _{IN} and X _{OUT} . When an external clock is used, the clock source should be connected to the X _{IN} pin and the X _{OUT} pin should be left open.
X _{OUT}	Clock output	Output	
E	Enable output	Output	Data or instruction read and data write are performed when output from this pin is "L".
BYTE	Bus width selection input	Input	In memory expansion mode or microprocessor mode, this pin determines whether the external data bus is 8-bit width or 16-bit width. The width is 16 bits when "L" signal inputs and 8 bits when "H" signal inputs.
AV _{CC} , AV _{SS}	Analog supply input		Power supply for the A-D converter. AV _{SS} is also used for D-A converter. Connect AV _{CC} to V _{CC} and AV _{SS} to V _{SS} externally.
V _{REF}	Reference voltage input	Input	This is reference voltage input pin for the A-D converter and the D-A converter.
P0 ₀ ~P0 ₇	I/O port P0	I/O	In single-chip mode, port P0 becomes an 8-bit I/O port. An I/O direction register is available so that each pin can be programmed for input or output. These ports are in input mode when reset. Address(A ₇ ~A ₀) is output in memory expansion mode or microprocessor mode.
P1 ₀ ~P1 ₇	I/O port P1	I/O	In single-chip mode, these pins have the same functions as port P0. When the BYTE pin is set to "L" in memory expansion mode or microprocessor mode and external data bus is 16-bit width, high-order data (D ₁₅ ~D ₈) is input or output when E output is "L" and an address (A ₁₅ ~A ₈) is output when E output is "H". If the BYTE pin is "H" that is an external data bus is 8-bit width, only address(A ₁₅ ~A ₈) is output.
P2 ₀ ~P2 ₇	I/O port P2	I/O	In single-chip mode, these pins have the same functions as port P0. In memory expansion mode or microprocessor mode low-order data(D ₇ ~D ₀) is input or output when E output is "L" and an address(A ₂₃ ~A ₁₆) is output when E output is "H".
P3 ₀ ~P3 ₃	I/O port P3	I/O	In single-chip mode, these pins have the same functions as port P0. In memory expansion mode or microprocessor mode, R/W, BHE, ALE, and HLDA signals are output.
P4 ₀ ~P4 ₇	I/O port P4	I/O	In single-chip mode, these pins have the same functions as port P0. In memory expansion mode or microprocessor mode, P4 ₀ and P4 ₁ become HOLD and RDY input pin respectively. Functions of other pins are the same as in single-chip mode. In single-chip mode or memory expansion mode, port P4 ₂ can be programmed for φ ₁ output pin divided the clock to X _{IN} pin by 2. In microprocessor mode, P4 ₂ always has the function as φ ₁ output pin.
P5 ₀ ~P5 ₇	I/O port P5	I/O	In addition to having the same functions as port P0 in single-chip mode, these pins also function as I/O pins for timer A0, timer A1, timer A2 and timer A3. P5 ₀ ~P5 ₆ also function as output pins for pulse motor drive waveform.
P6 ₀ ~P6 ₇	I/O port P6	I/O	In addition to having the same functions as port P0 in single-chip mode, these pins also function as I/O pins for timer A4, external interrupt input INT ₀ , INT ₁ and INT ₂ pins, and input pins for timer B0, timer B1 and timer B2. P6 ₀ also functions as output pin for pulse motor drive waveform.
P7 ₀ ~P7 ₇	I/O port P7	I/O	In addition to having the same functions as port P0 in single-chip mode, these pins also function as analog input AN ₀ ~AN ₇ input pins. P7 ₇ also has an A-D conversion trigger input function.
P8 ₀ ~P8 ₇	I/O port P8	I/O	In addition to having the same functions as port P0 in single-chip mode, these pins also function as RxD, TxD, CLK, CTS/RTS pins for UART 0 and UART 1, and output pins for D-A converter.

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

BASIC FUNCTION BLOCKS

The M37710M4LXXXFP has the same functions as the M37710M4BXXXFP except for the reset circuit.

Therefore, refer to the section on the M37710M4BXXXFP.

MEMORY

The memory map is shown in Figure 1.

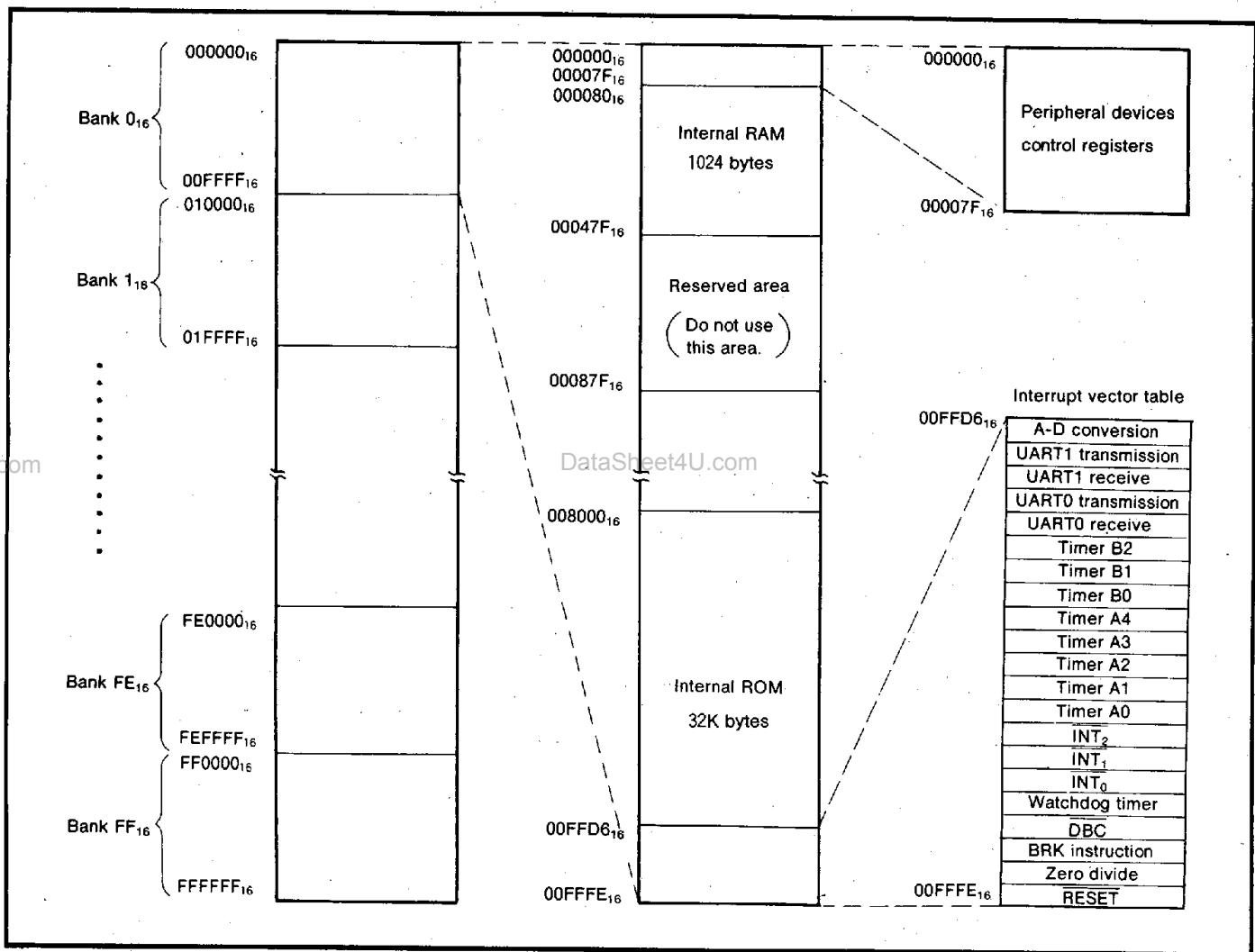


Fig. 1 Memory map

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

RESET CIRCUIT

Reset occurs when the RESET pin is returned to "H" level after holding it at "L" level when the power voltage is at 2.7 to 5.5V. Program execution starts at the address formed by setting the address pins $A_{23} \sim A_{16}$ to 00_{16} , $A_{15} \sim A_8$ to the contents of address $FFFF_{16}$, and $A_7 \sim A_0$ to the contents of address $FFFE_{16}$.

Figure 2 shows the status of the internal registers when a reset occurs.

Figure 3 shows an example of a reset circuit. The reset input voltage must be held 0.55V or lower when the power voltage reaches 2.7V.

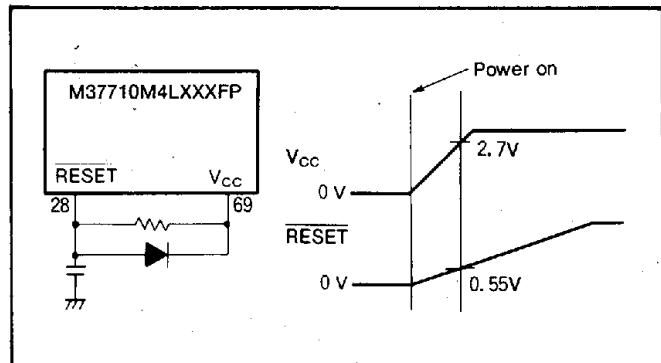


Fig. 3 Example of a reset circuit (perform careful evaluation at the system design level before using)

Address		Address			
(1) Port P0 data direction register	(04 ₁₆)...	00 ₁₆	(29) Processor mode register 0	(5E ₁₆)...	00 ₁₆
(2) Port P1 data direction register	(05 ₁₆)...	00 ₁₆	(30) Processor mode register 1	(5F ₁₆)...	X X X X X X X X 0
(3) Port P2 data direction register	(08 ₁₆)...	00 ₁₆	(31) Watchdog timer	(60 ₁₆)...	FFF ₁₆
(4) Port P3 data direction register	(09 ₁₆)...	X X X X X 0 0 0 0	(32) Watchdog timer frequency selection flag	(61 ₁₆)...	X X X X X X X X 0
(5) Port P4 data direction register	(0C ₁₆)...	00 ₁₆	(33) Waveform output mode register	(62 ₁₆)...	00 ₁₆
(6) Port P5 data direction register	(0D ₁₆)...	00 ₁₆	(34) Reserved area (Do not write to this address)	(66 ₁₆)...	00 ₁₆
(7) Port P6 data direction register	(10 ₁₆)...	00 ₁₆	(35) A-D conversion interrupt control register	(70 ₁₆)...	X X X X 0 0 0 0
(8) Port P7 data direction register	(11 ₁₆)...	00 ₁₆	(36) UART 0 transmission interrupt control register	(71 ₁₆)...	X X X X 0 0 0 0
(9) Port P8 data direction register	(14 ₁₆)...	00 ₁₆	(37) UART 0 receive interrupt control register	(72 ₁₆)...	X X X X 0 0 0 0
(10) A-D control register 0	(1E ₁₆)...	0 0 0 0 0 ? ? ?	(38) UART 1 transmission interrupt control register	(73 ₁₆)...	X X X X 0 0 0 0
(11) A-D control register 1	(1F ₁₆)...	0 0 X 0 0 0 1 1	(39) UART 1 receive interrupt control register	(74 ₁₆)...	X X X X 0 0 0 0
(12) UART 0 Transmit/Receive mode register	(30 ₁₆)...	00 ₁₆	(40) Timer A0 interrupt control register	(75 ₁₆)...	X X X X 0 0 0 0
(13) UART 1 Transmit/Receive mode register	(38 ₁₆)...	00 ₁₆	(41) Timer A1 interrupt control register	(76 ₁₆)...	X X X X 0 0 0 0
(14) UART 0 Transmit/Receive control register 0	(34 ₁₆)...	X X X 0 1 0 0 0	(42) Timer A2 interrupt control register	(77 ₁₆)...	X X X X 0 0 0 0
(15) UART 1 Transmit/Receive control register 0	(3C ₁₆)...	X X X 0 1 0 0 0	(43) Timer A3 interrupt control register	(78 ₁₆)...	X X X X 0 0 0 0
(16) UART 0 Transmit/Receive control register 1	(35 ₁₆)...	0 0 0 0 0 0 1 0	(44) Timer A4 interrupt control register	(79 ₁₆)...	X X X X 0 0 0 0
(17) UART 1 Transmit/Receive control register 1	(3D ₁₆)...	0 0 0 0 0 0 1 0	(45) Timer B0 interrupt control register	(7A ₁₆)...	X X X X 0 0 0 0
(18) Count start flag	(40 ₁₆)...	00 ₁₆	(46) Timer B1 interrupt control register	(7B ₁₆)...	X X X X 0 0 0 0
(19) One-shot start flag	(42 ₁₆)...	X X X 0 0 0 0 0	(47) Timer B2 interrupt control register	(7C ₁₆)...	X X X X 0 0 0 0
(20) Up-down flag	(44 ₁₆)...	00 ₁₆	(48) INT ₀ interrupt control register	(7D ₁₆)...	X X 0 0 0 0 0 0
(21) Timer A0 mode register	(56 ₁₆)...	00 ₁₆	(49) INT ₁ interrupt control register	(7E ₁₆)...	X X 0 0 0 0 0 0
(22) Timer A1 mode register	(57 ₁₆)...	00 ₁₆	(50) INT ₂ interrupt control register	(7F ₁₆)...	X X 0 0 0 0 0 0
(23) Timer A2 mode register	(58 ₁₆)...	00 ₁₆	(51) Processor status register PS		0 0 0 ? ? 0 0 0 1 ? ?
(24) Timer A3 mode register	(59 ₁₆)...	00 ₁₆	(52) Program bank register PG		00 ₁₆
(25) Timer A4 mode register	(5A ₁₆)...	00 ₁₆	(53) Program counter PC _H		Content of FFFF ₁₆
(26) Timer B0 mode register	(5B ₁₆)...	0 0 1 0 0 0 0 0	(54) Program counter PC _L		Content of FFFE ₁₆
(27) Timer B1 mode register	(5C ₁₆)...	0 0 1 X 0 0 0 0	(55) Direct page register DPR		0000 ₁₆
(28) Timer B2 mode register	(5D ₁₆)...	0 0 1 X 0 0 0 0	(56) Data bank register DT		00 ₁₆

Contents of other registers and RAM are not initialized and should be initialized by software.

Fig. 2 Microcomputer internal status during reset

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

ADDRESSING MODES

The M37710M4LXXXFP has 28 powerful addressing modes. Refer to the 7700 Family addressing mode description for the details of each addressing mode.

MACHINE INSTRUCTION LIST

The M37710M4LXXXFP has 103 machine instructions. Refer to the 7700 Family machine instruction list for details.

DATA REQUIRED FOR MASK ROM ORDERING

Please send the following data for mask orders.

- (1) M37710M4LXXXFP mask ROM order confirmation form
- (2) 80P6N mark specification form
- (3) ROM data.(EPROM 3 sets)

MITSUBISHI MICROCOMPUTERS
M37710M4LXXXFP

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Conditions	Ratings	Unit
V_{CC}	Supply voltage		-0.3~7	V
AV_{CC}	Analog supply voltage		-0.3~7	V
V_I	Input voltage RESET, CNV _{SS} , BYTE		-0.3~12	V
V_I	Input voltage P ₀ ~P ₇ , P ₁ ~P ₇ , P ₂ ~P ₇ , P ₃ ~P ₃ , P ₄ ~P ₇ , P ₅ ~P ₇ , P ₆ ~P ₇ , P ₇ ~P ₇ , P ₈ ~P ₇ , V _{REF} , X _{IN}		-0.3~ V_{CC} +0.3	V
V_O	Output voltage P ₀ ~P ₇ , P ₁ ~P ₇ , P ₂ ~P ₇ , P ₃ ~P ₃ , P ₄ ~P ₇ , P ₅ ~P ₇ , P ₆ ~P ₇ , P ₇ ~P ₇ , P ₈ ~P ₇ , X _{OUT} , E		-0.3~ V_{CC} +0.3	V
P_d	Power dissipation	T _a =25°C	300	mW
T _{opr}	Operating temperature		-40~85	°C
T _{stg}	Storage temperature		-65~150	°C

RECOMMENDED OPERATING CONDITIONS ($V_{CC}=2.7\sim 5.5V$, $T_a=-40\sim 85^{\circ}C$, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min.	Typ.	Max.	
V_{CC}	Supply voltage	2.7		5.5	V
AV_{CC}	Analog supply voltage		V_{CC}		V
V_{SS}	Supply voltage		0		V
AV_{SS}	Analog supply voltage		0		V
V_{IH}	High-level input voltage P ₀ ~P ₇ , P ₃ ~P ₃ , P ₄ ~P ₇ , P ₅ ~P ₇ , P ₆ ~P ₇ , P ₇ ~P ₇ , P ₈ ~P ₇ , X _{IN} , RESET, CNV _{SS} , BYTE	0.8 V_{CC}		V_{CC}	V
V_{IH}	High-level input voltage P ₁ ~P ₇ , P ₂ ~P ₇ (in single-chip mode)	0.8 V_{CC}		V_{CC}	V
V_{IH}	High-level input voltage P ₁ ~P ₇ , P ₂ ~P ₇ (in memory expansion mode and microprocessor mode)	0.5 V_{CC}		V_{CC}	V
V_{IL}	Low-level input voltage P ₀ ~P ₇ , P ₃ ~P ₃ , P ₄ ~P ₇ , P ₅ ~P ₇ , P ₆ ~P ₇ , P ₇ ~P ₇ , P ₈ ~P ₇ , X _{IN} , RESET, CNV _{SS} , BYTE	0		0.2 V_{CC}	V
V_{IL}	Low-level input voltage P ₁ ~P ₇ , P ₂ ~P ₇ (in single-chip mode)	0		0.2 V_{CC}	V
V_{IL}	Low-level input voltage P ₁ ~P ₇ , P ₂ ~P ₇ (in memory expansion mode and microprocessor mode)	0		0.16 V_{CC}	V
$I_{OH(peak)}$	High-level peak output current P ₀ ~P ₇ , P ₁ ~P ₇ , P ₂ ~P ₇ , P ₃ ~P ₃ , P ₄ ~P ₇ , P ₅ ~P ₇ , P ₆ ~P ₇ , P ₇ ~P ₇ , P ₈ ~P ₇			-10	mA
$I_{OH(avg)}$	High-level average output current P ₀ ~P ₇ , P ₁ ~P ₇ , P ₂ ~P ₇ , P ₃ ~P ₃ , P ₄ ~P ₇ , P ₅ ~P ₇ , P ₆ ~P ₇ , P ₇ ~P ₇ , P ₈ ~P ₇			-5	mA
$I_{OL(peak)}$	Low-level peak output current P ₀ ~P ₇ , P ₁ ~P ₇ , P ₂ ~P ₇ , P ₃ ~P ₃ , P ₄ ~P ₇ , P ₅ ~P ₇ , P ₆ ~P ₇ , P ₇ ~P ₇ , P ₈ ~P ₇			10	mA
$I_{OL(avg)}$	Low-level average output current P ₀ ~P ₇ , P ₁ ~P ₇ , P ₂ ~P ₇ , P ₃ ~P ₃ , P ₄ ~P ₇ , P ₅ ~P ₇ , P ₆ ~P ₇ , P ₇ ~P ₇ , P ₈ ~P ₇			5	mA
f(X _{IN})	External clock frequency input			8	MHz

Notes 1. Average output current is the average value of a 100ms interval.

2. The sum of $I_{OL(peak)}$ for ports P0, P1, P2, P3, and P8 must be 80mA or less,
the sum of $I_{OH(peak)}$ for ports P0, P1, P2, P3, and P8 must be 80mA or less,
the sum of $I_{OL(peak)}$ for ports P4, P5, P6, and P7 must be 80mA or less, and
the sum of $I_{OH(peak)}$ for ports P4, P5, P6, and P7 must be 80mA or less.

MITSUBISHI MICROCOMPUTERS
M37710M4LXXXFP

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

ELECTRICAL CHARACTERISTICS ($V_{CC}=5V$, $V_{SS}=0V$, $T_a=25^\circ C$, $f(X_{IN})=8MHz$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V_{OH}	High-level output voltage $P0_0 \sim P0_7$, $P1_0 \sim P1_7$, $P2_0 \sim P2_7$, $P3_0$, $P3_1$, $P3_3$, $P4_0 \sim P4_7$, $P5_0 \sim P5_7$, $P6_0 \sim P6_7$, $P7_0 \sim P7_7$, $P8_0 \sim P8_7$	$V_{CC}=5V$, $I_{OH}=-10mA$	3			V
		$V_{CC}=3V$, $I_{OH}=-1mA$	2.5			
V_{OH}	High-level output voltage $P0_0 \sim P0_7$, $P1_0 \sim P1_7$, $P2_0 \sim P2_7$, $P3_0$, $P3_1$, $P3_3$	$V_{CC}=5V$, $I_{OH}=-400\mu A$	4.7			V
V_{OH}	High-level output voltage $P3_2$	$V_{CC}=5V$, $I_{OH}=-10mA$	3.1			V
		$V_{CC}=5V$, $I_{OH}=-400\mu A$	4.8			
		$V_{CC}=3V$, $I_{OH}=-1mA$	2.6			
V_{OH}	High-level output voltage \bar{E}	$V_{CC}=5V$, $I_{OH}=-10mA$	3.4			V
		$V_{CC}=5V$, $I_{OH}=-400\mu A$	4.8			
		$V_{CC}=3V$, $I_{OH}=-1mA$	2.6			
V_{OL}	Low-level output voltage $P0_0 \sim P0_7$, $P1_0 \sim P1_7$, $P2_0 \sim P2_7$, $P3_0$, $P3_1$, $P3_3$, $P4_0 \sim P4_7$, $P5_0 \sim P5_7$, $P6_0 \sim P6_7$, $P7_0 \sim P7_7$, $P8_0 \sim P8_7$	$V_{CC}=5V$, $I_{OL}=10mA$			2	V
		$V_{CC}=3V$, $I_{OL}=1mA$			0.5	
V_{OL}	Low-level output voltage $P0_0 \sim P0_7$, $P1_0 \sim P1_7$, $P2_0 \sim P2_7$, $P3_0$, $P3_1$, $P3_3$	$V_{CC}=5V$, $I_{OL}=2mA$			0.45	V
V_{OL}	Low-level output voltage $P3_2$	$V_{CC}=5V$, $I_{OL}=10mA$			1.9	V
		$V_{CC}=5V$, $I_{OL}=2mA$			0.43	
		$V_{CC}=3V$, $I_{OL}=1mA$			0.4	
V_{OL}	Low-level output voltage \bar{E}	$V_{CC}=5V$, $I_{OL}=10mA$			1.6	V
		$V_{CC}=5V$, $I_{OL}=2mA$			0.4	
		$V_{CC}=3V$, $I_{OL}=1mA$			0.4	
$V_{TT}-V_{T-}$	Hysteresis HOLD, RDY, $TA0_{IN} \sim TA4_{IN}$, $TB0_{IN} \sim TB2_{IN}$, $INT_0 \sim INT_2$, AD_{TRG} , CTS_0 , CTS_1 , CLK_0 , CLK_1	$V_{CC}=5V$	0.4		1	V
		$V_{CC}=3V$	0.1		0.7	
$V_{TT}-V_{T-}$	Hysteresis RESET	$V_{CC}=5V$	0.2		0.5	V
		$V_{CC}=3V$	0.1		0.4	
$V_{TT}-V_{T-}$	Hysteresis X_{IN}	$V_{CC}=5V$	0.1		0.3	V
		$V_{CC}=3V$	0.06		0.2	
I_{IH}	High-level input current $P0_0 \sim P0_7$, $P1_0 \sim P1_7$, $P2_0 \sim P2_7$, $P3_0 \sim P3_3$, $P4_0 \sim P4_7$, $P5_0 \sim P5_7$, $P6_0 \sim P6_7$, $P7_0 \sim P7_7$, $P8_0 \sim P8_7$, X_{IN} , RESET, CNV_{SS} , BYTE	$V_{CC}=5V$, $V_I=5V$			5	μA
		$V_{CC}=3V$, $V_I=3V$			4	
I_{IL}	Low-level input current $P0_0 \sim P0_7$, $P1_0 \sim P1_7$, $P2_0 \sim P2_7$, $P3_0 \sim P3_3$, $P4_0 \sim P4_7$, $P5_0 \sim P5_7$, $P6_0 \sim P6_7$, $P7_0 \sim P7_7$, $P8_0 \sim P8_7$, X_{IN} , RESET, CNV_{SS} , BYTE	$V_{CC}=5V$, $V_I=0V$			-5	μA
		$V_{CC}=3V$, $V_I=0V$			-4	
V_{RAM}	RAM hold voltage	When clock is stopped.	2			V
I_{CC}	Power supply current	In single-chip mode output only pin is open and other pins are V_{SS} during reset.	$f(X_{IN})=8MHz$, $V_{CC}=5V$	6	12	mA
			$V_{CC}=3V$	4	8	
		Ta=25°C when clock is stopped.			1	μA
			$Ta=85^\circ C$ when clock is stopped.			
					20	

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER**A-D CONVERTER CHARACTERISTICS** ($V_{CC}=AV_{CC}=5V$, $V_{SS}=AV_{SS}=0V$, $T_a=25^\circ C$, $f(X_{IN})=8MHz$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
—	Resolution	$V_{REF}=V_{CC}$			10	Bits
—	Absolute accuracy	$V_{REF}=V_{CC}$			± 3	LSB
R_{LADDER}	Ladder resistance	$V_{REF}=V_{CC}$	5		20	$k\Omega$
t_{CONV}	Conversion time		29.5			μs
V_{REF}	Reference voltage		2.7		V_{CC}	V
V_{IA}	Analog input voltage		0		V_{REF}	V

D-A CONVERTER CHARACTERISTICS ($V_{CC}=5V$, $V_{SS}=AV_{SS}=0V$, $V_{REF}=5V$, $T_a=25^\circ C$, $f(X_{IN})=8MHz$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
—	Resolution				8	Bits
—	Absolute accuracy				1.0	%
t_{SU}	Set time				3	μs
R_o	Output resistance		1	2.5	4	$k\Omega$
I_{VREF}	Reference power input current	(Note)			3.2	mA

Note. One D-A converter is used, and the value of D-A register for unused D-A converter is "00₁₆".
Current that flows to the ladder resistance of A-D converter is excluded.

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

TIMING REQUIREMENTS ($V_{CC}=2.7\sim 5.5V$, $V_{SS}=0V$, $T_a=25^\circ C$, $f(X_{IN})=8MHz$, unless otherwise noted)

External clock input

Symbol	Parameter	Limits		Unit
		Min.	Max.	
t_c	External clock input cycle time	125		ns
$t_{W(H)}$	External clock input high-level pulse width	50		ns
$t_{W(L)}$	External clock input low-level pulse width	50		ns
t_r	External clock rise time		20	ns
t_f	External clock fall time		20	ns

Single-chip mode

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{SU(P0D-E)}$	Port P0 input setup time	300		ns
$t_{SU(P1D-E)}$	Port P1 input setup time	300		ns
$t_{SU(P2D-E)}$	Port P2 input setup time	300		ns
$t_{SU(P3D-E)}$	Port P3 input setup time	300		ns
$t_{SU(P4D-E)}$	Port P4 input setup time	300		ns
$t_{SU(P5D-E)}$	Port P5 input setup time	300		ns
$t_{SU(P6D-E)}$	Port P6 input setup time	300		ns
$t_{SU(P7D-E)}$	Port P7 input setup time	300		ns
$t_{SU(P8D-E)}$	Port P8 input setup time	300		ns
$t_h(E-P0D)$	Port P0 input hold time	0		ns
$t_h(E-P1D)$	Port P1 input hold time	0		ns
$t_h(E-P2D)$	Port P2 input hold time	0		ns
$t_h(E-P3D)$	Port P3 input hold time	0		ns
$t_h(E-P4D)$	Port P4 input hold time	0		ns
$t_h(E-P5D)$	Port P5 input hold time	0		ns
$t_h(E-P6D)$	Port P6 input hold time	0		ns
$t_h(E-P7D)$	Port P7 input hold time	0		ns
$t_h(E-P8D)$	Port P8 input hold time	0		ns

DataSheet4U.com

DataSheet4U.com

Memory expansion mode and microprocessor mode

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{SU(P1D-E)}$	Port P1 input setup time	80		ns
$t_{SU(P2D-E)}$	Port P2 input setup time	80		ns
$t_{SU(RDY-\phi_1)}$	RDY input setup time	90		ns
$t_{SU(HOLD-\phi_1)}$	HOLD input setup time	90		ns
$t_h(E-P1D)$	Port P1 input hold time	0		ns
$t_h(E-P2D)$	Port P2 input hold time	0		ns
$t_h(\phi_1-RDY)$	RDY input hold time	0		ns
$t_h(\phi_1-HOLD)$	HOLD input hold time	0		ns

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER**Timer A input** (Count input in event counter mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TA)}$	TA _{iN} input cycle time	250		ns
$t_{W(TAH)}$	TA _{iN} input high-level pulse width	125		ns
$t_{W(TAL)}$	TA _{iN} input low-level pulse width	125		ns

Timer A input (Gating input in timer mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TA)}$	TA _{iN} input cycle time	1000		ns
$t_{W(TAH)}$	TA _{iN} input high-level pulse width	500		ns
$t_{W(TAL)}$	TA _{iN} input low-level pulse width	500		ns

Timer A input (External trigger input in one-shot pulse mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TA)}$	TA _{iN} input cycle time	500		ns
$t_{W(TAH)}$	TA _{iN} input high-level pulse width	250		ns
$t_{W(TAL)}$	TA _{iN} input low-level pulse width	250		ns

DataSheet4U.com DataSheet4U.com DataSheet4U.com
Timer A input (External trigger input in pulse width modulation mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{W(TAH)}$	TA _{iN} input high-level pulse width	250		ns
$t_{W(TAL)}$	TA _{iN} input low-level pulse width	250		ns

Timer A input (Up-down input in event counter mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(UP)}$	TA _{iout} input cycle time	5000		ns
$t_{W(UPH)}$	TA _{iout} input high-level pulse width	2500		ns
$t_{W(UPL)}$	TA _{iout} input low-level pulse width	2500		ns
$t_{SU(UP-TIN)}$	TA _{iout} input setup time	1000		ns
$t_{h(TIN-UP)}$	TA _{iout} input hold time	1000		ns

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER**Timer B input** (Count input in event counter mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TB)}$	TBi _{IN} input cycle time (one edge count)	250		ns
$t_{W(TBH)}$	TBi _{IN} input high-level pulse width (one edge count)	125		ns
$t_{W(TBL)}$	TBi _{IN} input low-level pulse width (one edge count)	125		ns
$t_{C(TB)}$	TBi _{IN} input cycle time (both edges count)	500		ns
$t_{W(TBH)}$	TBi _{IN} input high-level pulse width (both edges count)	250		ns
$t_{W(TBL)}$	TBi _{IN} input low-level pulse width (both edges count)	250		ns

Timer B input (Pulse period measurement mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TB)}$	TBi _{IN} input cycle time	1000		ns
$t_{W(TBH)}$	TBi _{IN} input high-level pulse width	500		ns
$t_{W(TBL)}$	TBi _{IN} input low-level pulse width	500		ns

Timer B input (Pulse width measurement mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TB)}$	TBi _{IN} input cycle time	1000		ns
$t_{W(TBH)}$	TBi _{IN} input high-level pulse width	500		ns
$t_{W(TBL)}$	TBi _{IN} input low-level pulse width	500		ns

A-D trigger input

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(AD)}$	AD _{TRG} input cycle time (minimum allowable trigger)	2000		ns
$t_{W(ADL)}$	AD _{TRG} input low-level pulse width	250		ns

Serial I/O

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(CK)}$	CLK _i input cycle time	500		ns
$t_{W(CKH)}$	CLK _i input high-level pulse width	250		ns
$t_{W(CKL)}$	CLK _i input low-level pulse width	250		ns
$t_d(c-a)$	TxD _j output delay time		170	ns
$t_h(c-a)$	TxD _j hold time	0		ns
$t_{su(p-c)}$	RxD _j input setup time	80		ns
$t_h(c-p)$	RxD _j input hold time	100		ns

External interrupt INT_i input

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{W(INH)}$	INT _i input high-level pulse width	250		ns
$t_{W(INL)}$	INT _i input low-level pulse width	250		ns

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

SWITCHING CHARACTERISTICS ($V_{CC}=2.7\sim 5.5V$, $V_{SS}=0V$, $T_a=25^\circ C$, $f(X_{IN})=8MHz$, unless otherwise noted)

Single-chip mode

Symbol	Parameter	Test conditions		Limits	Unit
		Min.	Max.		
$t_{d(E-P0Q)}$	Port P0 data output delay time	Fig. 4		300	ns
$t_{d(E-P1Q)}$	Port P1 data output delay time			300	ns
$t_{d(E-P2Q)}$	Port P2 data output delay time			300	ns
$t_{d(E-P3Q)}$	Port P3 data output delay time			300	ns
$t_{d(E-P4Q)}$	Port P4 data output delay time			300	ns
$t_{d(E-P5Q)}$	Port P5 data output delay time			300	ns
$t_{d(E-P6Q)}$	Port P6 data output delay time			300	ns
$t_{d(E-P7Q)}$	Port P7 data output delay time			300	ns
$t_{d(E-P8Q)}$	Port P8 data output delay time			300	ns

Memory expansion mode and microprocessor mode (when wait bit = "1")

Symbol	Parameter	Test conditions		Limits	Unit
		Min.	Max.		
$t_{d(P0A-E)}$	Port P0 address output delay time	Fig. 4		62	ns
$t_{d(E-P1Q)}$	Port P1 data output delay time (BYTE="L")			130	ns
$tpzx(E-P1Z)$	Port P1 floating start delay time (BYTE="L")			10	ns
$t_{d(P1A-E)}$	Port P1 address output delay time			62	ns
$t_{d(P1A-ALE)}$	Port P1 address output delay time			52	ns
$t_{d(E-P2Q)}$	Port P2 data output delay time			130	ns
$tpzx(E-P2Z)$	Port P2 floating start delay time			10	ns
$t_{d(P2A-E)}$	Port P2 address output delay time			62	ns
$t_{d(P2A-ALE)}$	Port P2 address output delay time			52	ns
$t_{d(\phi_1-HLDA)}$	HLDA output delay time			120	ns
$t_{d(ALE-E)}$	ALE output delay time			4	ns
$t_w(ALE)$	ALE pulse width			82	ns
$t_{d(BHE-E)}$	BHE output delay time			62	ns
$t_{d(R/W-E)}$	R/W output delay time			62	ns
$t_{d(E-\phi_1)}$	ϕ_1 output delay time			0	40 ns
$t_h(E-P0A)$	Port P0 address hold time			95	ns
$t_h(ALE-P1A)$	Port P1 address hold time (BYTE="L")			9	ns
$t_h(E-P1Q)$	Port P1 data hold time (BYTE="L")			95	ns
$tpzx(E-P1Z)$	Port P1 floating release delay time (BYTE="L")			95	ns
$t_h(E-P1A)$	Port P1 address hold time (BYTE="H")			95	ns
$t_h(ALE-P2A)$	Port P2 address hold time			9	ns
$t_h(E-P2Q)$	Port P2 data hold time			95	ns
$tpzx(E-P2Z)$	Port P2 floating release delay time			95	ns
$t_h(E-BHE)$	BHE hold time			18	ns
$t_h(E-R/W)$	R/W hold time			18	ns
$t_w(EL)$	\bar{E} pulse width			220	ns

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER**Memory expansion mode and microprocessor mode**

(when wait bit = "0", wait selection bit = "1", and external memory area is accessed)

Symbol	Parameter	Test conditions	Limits		Unit
			Min.	Max.	
$t_d(P0A-E)$	Port P0 address output delay time		62		ns
$t_d(E-P1Q)$	Port P1 data output delay time (BYTE="L")			130	ns
$t_{pxz}(E-P1Z)$	Port P1 floating start delay time (BYTE="L")			10	ns
$t_d(P1A-E)$	Port P1 address output delay time		62		ns
$t_d(P1A-ALE)$	Port P1 address output delay time		52		ns
$t_d(E-P2Q)$	Port P2 data output delay time			130	ns
$t_{pxz}(E-P2Z)$	Port P2 floating start delay time			10	ns
$t_d(P2A-E)$	Port P2 address output delay time		62		ns
$t_d(P2A-ALE)$	Port P2 address output delay time		52		ns
$t_d(\phi_1-HLDA)$	HLDA output delay time			120	ns
$t_d(ALE-E)$	ALE output delay time		4		ns
$t_w(ALE)$	ALE pulse width		82		ns
$t_d(BHE-E)$	BHE output delay time		62		ns
$t_d(R/W-E)$	R/W output delay time		62		ns
$t_d(E-\phi_1)$	ϕ_1 output delay time		0	40	ns
$t_h(E-P0A)$	Port P0 address hold time		95		ns
$t_h(ALE-P1A)$	Port P1 address hold time (BYTE="L")		9		ns
$t_h(E-P1Q)$	Port P1 data hold time (BYTE="L")		95		ns
$t_{pxz}(E-P1Z)$	Port P1 floating release delay time (BYTE="L")		95		ns
$t_h(E-P1A)$	Port P1 address hold time (BYTE="H")		95		ns
$t_h(ALE-P2A)$	Port P2 address hold time		9		ns
$t_h(E-P2Q)$	Port P2 data hold time		95		ns
$t_{pxz}(E-P2Z)$	Port P2 floating release delay time		95		ns
$t_h(E-BHE)$	BHE hold time		18		ns
$t_h(E-R/W)$	R/W hold time		18		ns
$t_w(EL)$	E pulse width		470		ns

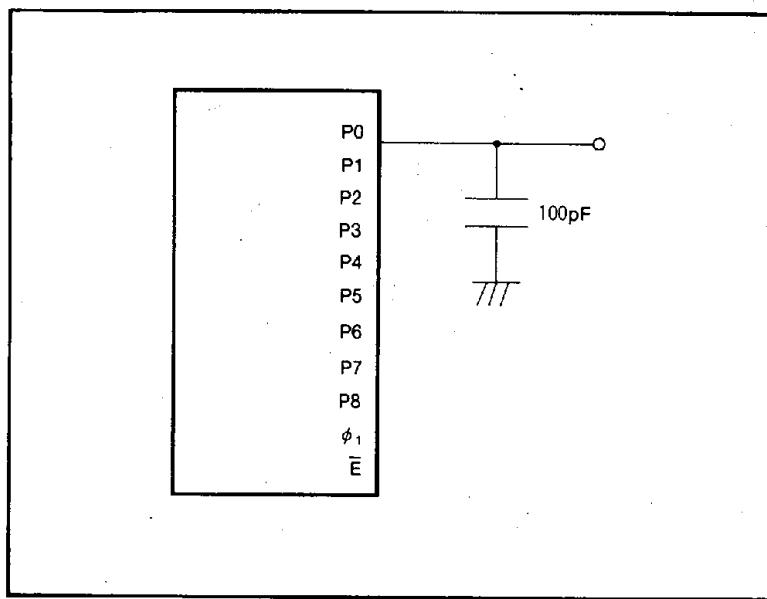
Fig. 4

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER**Memory expansion mode and microprocessor mode**

(when wait bit = "0", wait selection bit = "0", and external memory area is accessed)

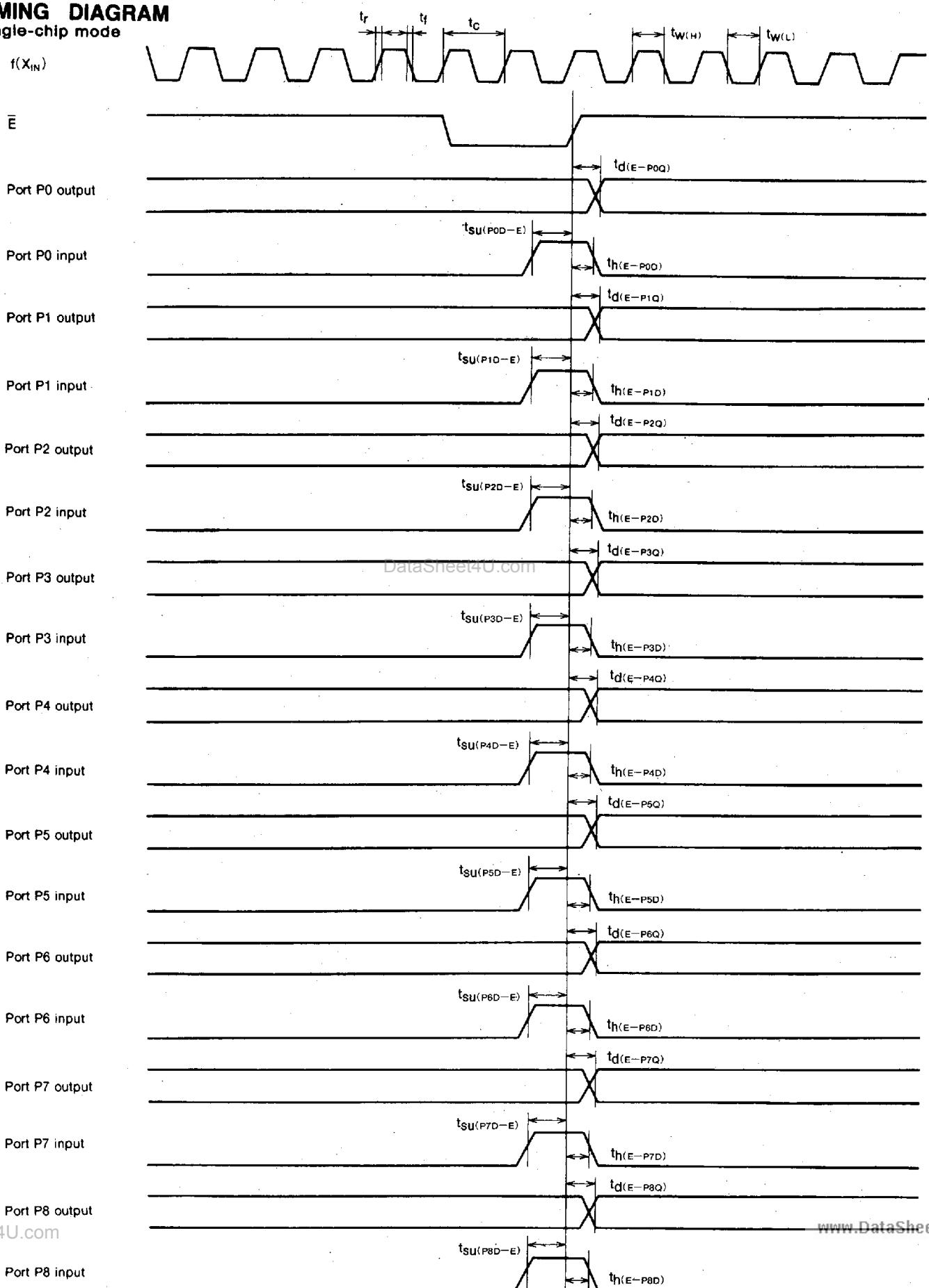
Symbol	Parameter	Test conditions	Limits		Unit
			Min.	Max.	
$t_d(P0A-E)$	Port P0 address output delay time		312		ns
$t_d(E-P1Q)$	Port P1 data output delay time (BYTE="L")			130	ns
$t_{pxz}(E-P1Z)$	Port P1 floating start delay time (BYTE="L")			10	ns
$t_d(P1A-E)$	Port P1 address output delay time		312		ns
$t_d(P1A-ALE)$	Port P1 address output delay time		177		ns
$t_d(E-P2Q)$	Port P2 data output delay time			130	ns
$t_{pxz}(E-P2Z)$	Port P2 floating start delay time			10	ns
$t_d(P2A-E)$	Port P2 address output delay time		312		ns
$t_d(P2A-ALE)$	Port P2 address output delay time		177		ns
$t_d(\phi_1-HLDA)$	HLDA output delay time			120	ns
$t_d(ALE-E)$	ALE output delay time		100		ns
$t_w(ALE)$	ALE pulse width		207		ns
$t_d(BHE-E)$	BHE output delay time		312		ns
$t_d(R/W-E)$	R/W output delay time		312		ns
$t_d(E-\phi_1)$	ϕ_1 output delay time		0	40	ns
$t_h(E-P0A)$	Port P0 address hold time		95		ns
$t_h(ALE-P1A)$	Port P1 address hold time (BYTE="L")		105		ns
$t_h(E-P1Q)$	Port P1 data hold time (BYTE="L")		95		ns
$t_{pxz}(E-P1Z)$	Port P1 floating release delay time (BYTE="L")		95		ns
$t_h(E-P1A)$	Port P1 address hold time (BYTE="H")		95		ns
$t_h(ALE-P2A)$	Port P2 address hold time		105		ns
$t_h(E-P2Q)$	Port P2 data hold time		95		ns
$t_{pxz}(E-P2Z)$	Port P2 floating release delay time		95		ns
$t_h(E-BHE)$	BHE hold time		18		ns
$t_h(E-R/W)$	R/W hold time		18		ns
$t_w(\bar{E})$	\bar{E} pulse width		470		ns

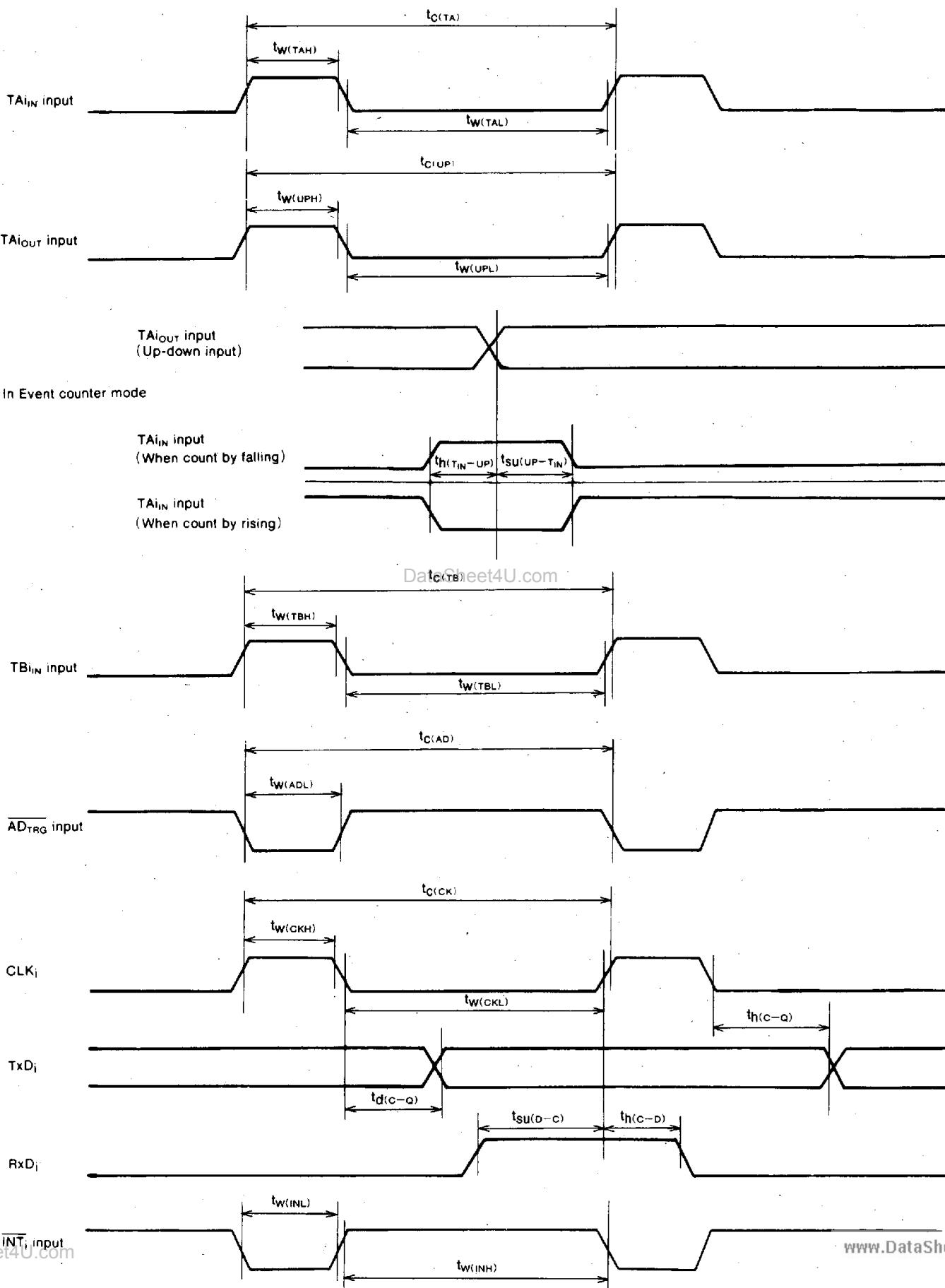
Fig. 4

Fig. 4 Testing circuit for ports P0~P8, ϕ_1

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER**TIMING DIAGRAM**

Single-chip mode



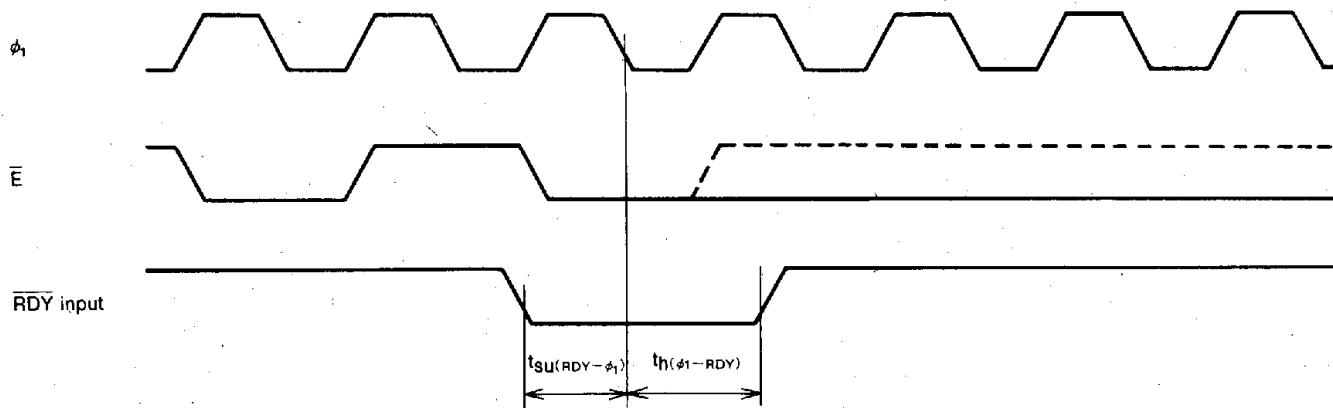
SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

MITSUBISHI MICROCOMPUTERS
M37710M4LXXXFP

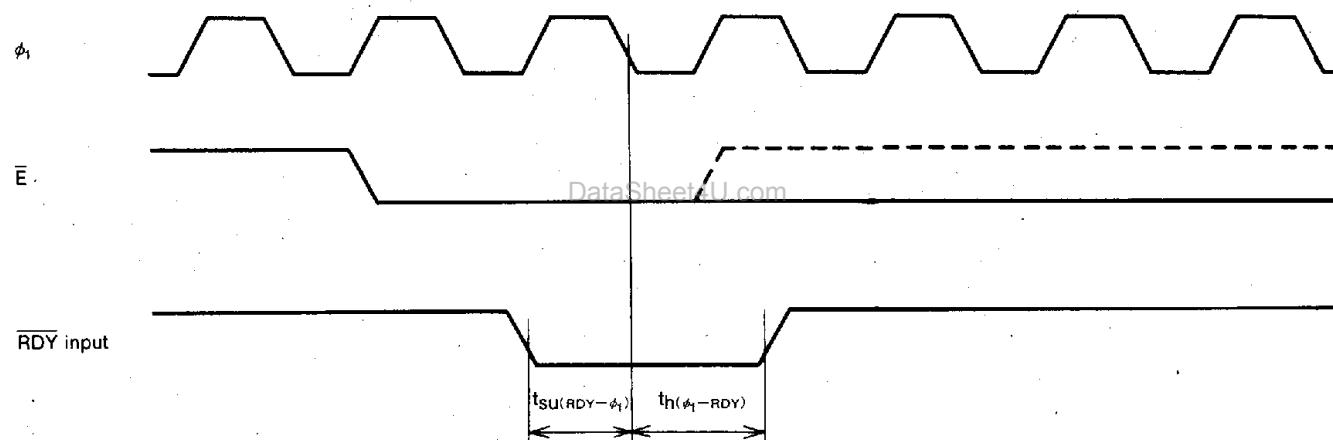
SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

Memory expansion mode and microprocessor mode

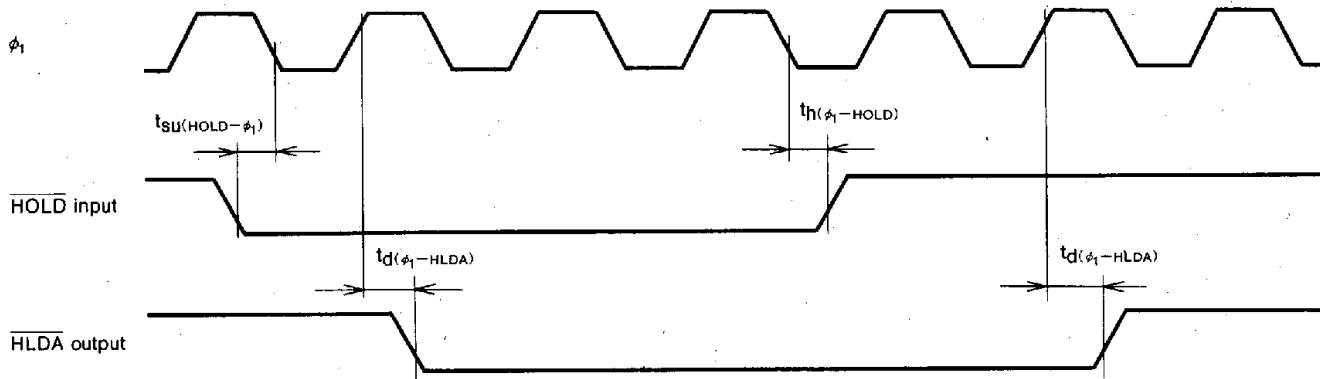
(When wait bit = "1")



(When wait bit = "0")



(When wait bit = "1" or "0" in common)

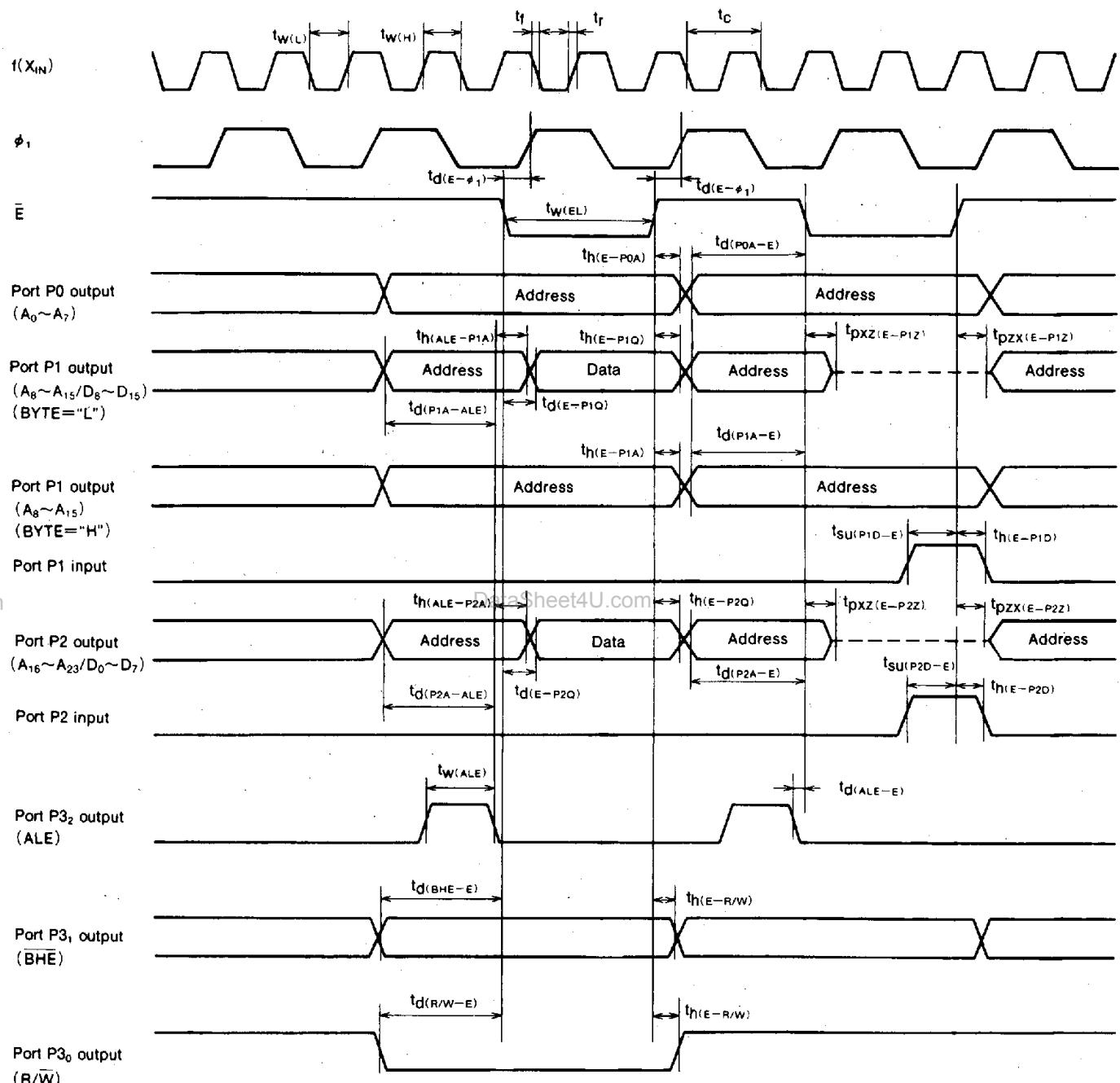


Test conditions

- $V_{CC} = 2.7 \sim 5.5V$
- Input timing voltage : $V_{IL} = 0.2V_{CC}$, $V_{IH} = 0.8V_{CC}$
- Output timing voltage : $V_{OL} = 0.8V$, $V_{OH} = 2.0V$

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

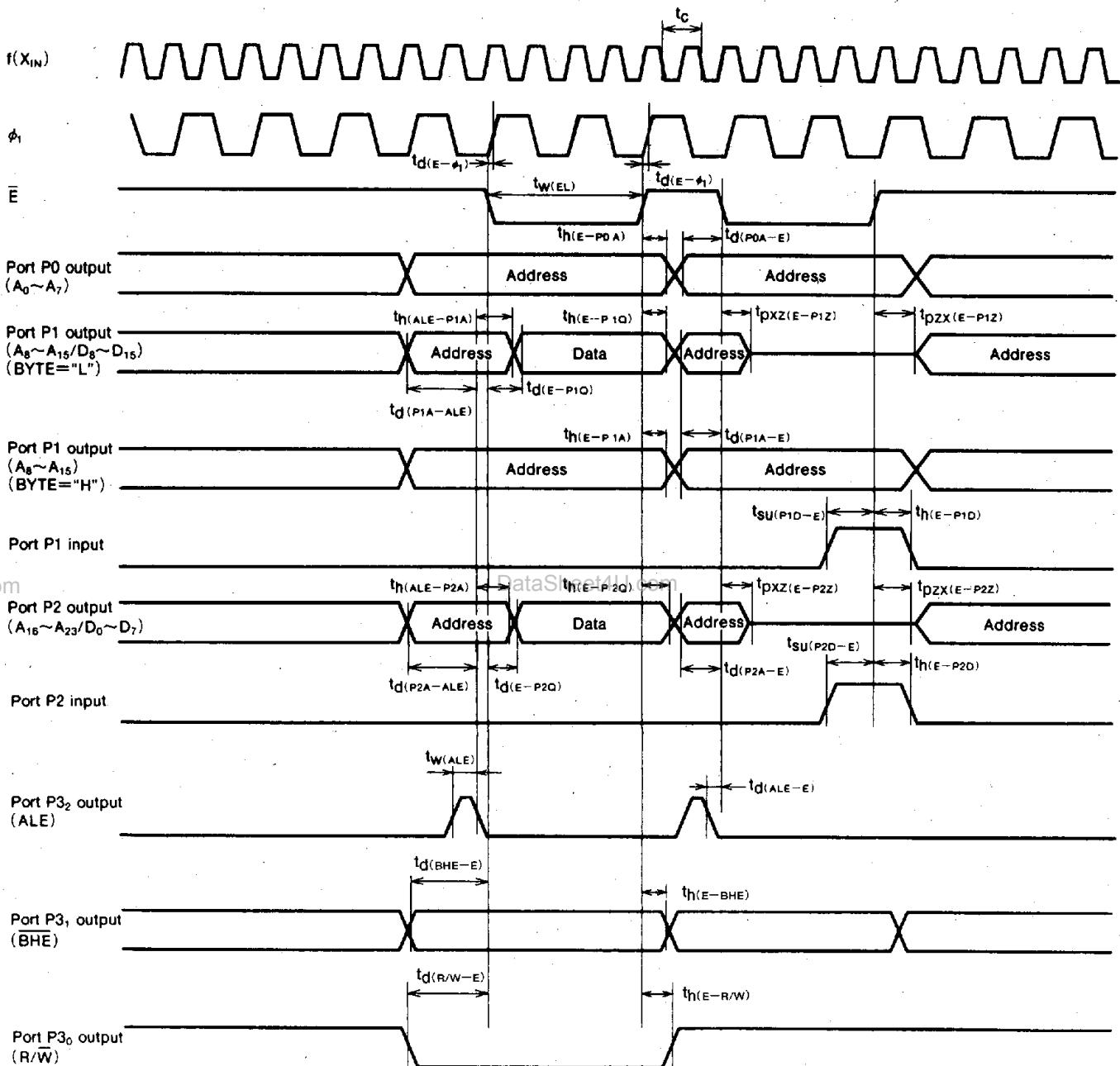
Memory expansion mode and microprocessor mode (When wait bit="1")

**Test conditions**

- $V_{CC}=2.7 \sim 5.5V$
- Output timing voltage : $V_{OL}=0.8V$, $V_{OH}=2.0V$
- Ports P1, P2 input : $V_{IL}=0.16V_{CC}$, $V_{IH}=0.5V_{CC}$

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER**Memory expansion mode and microprocessor mode**

(When wait bit = "0", wait selection bit = "1", and external memory area is accessed)

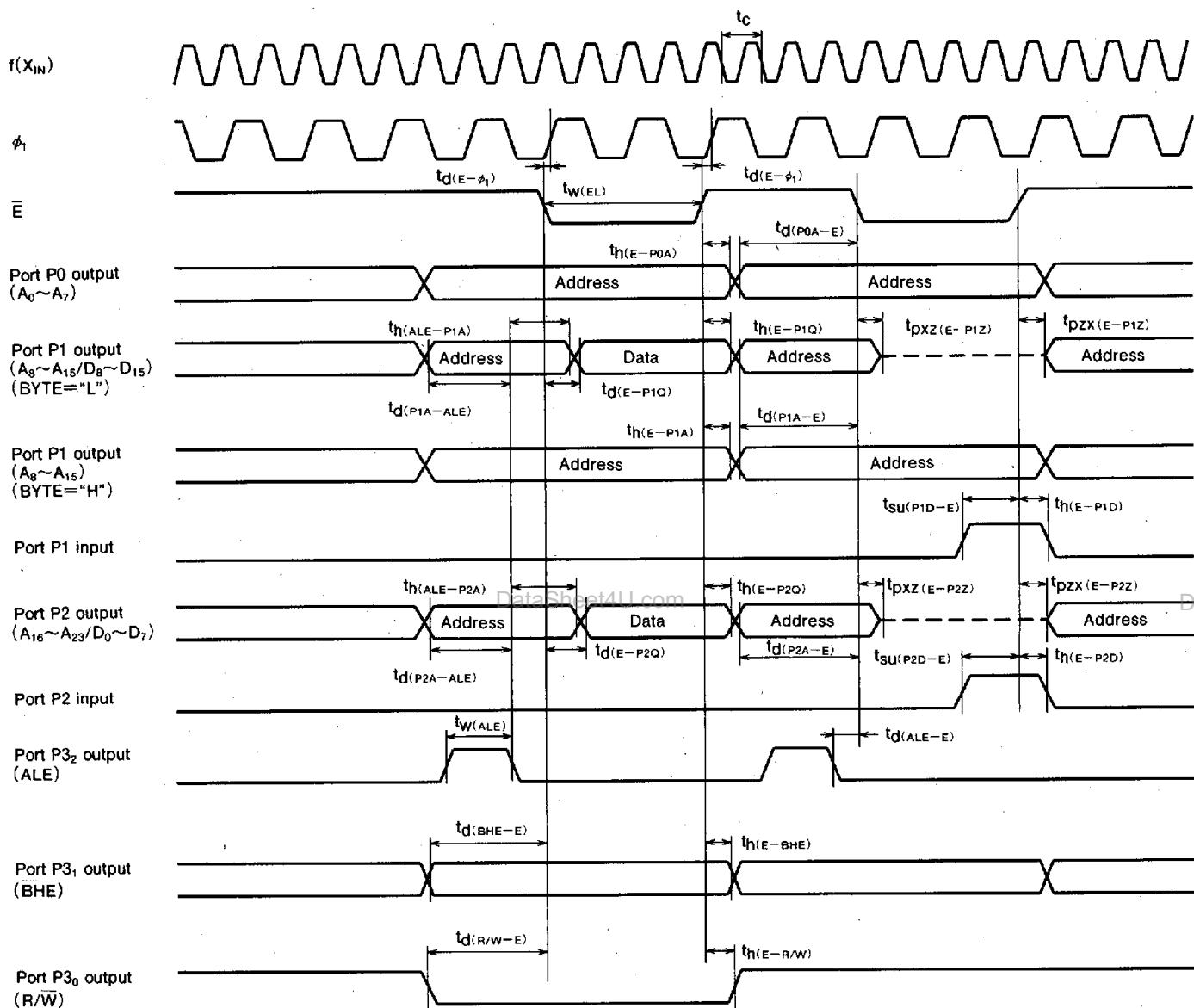
**Test conditions**

- $V_{CC}=2.7 \sim 5.5V$
- Output timing voltage : $V_{OL}=0.8V$, $V_{OH}=2.0V$
- Ports P1, P2 input : $V_{IL}=0.16V_{CC}$, $V_{IH}=0.5V_{CC}$

SINGLE-CHIP 16-BIT CMOS MICROCOMPUTER

Memory expansion mode and microprocessor mode

(When wait bit = "0", wait selection bit = "0", and external memory area is accessed)



Test conditions

- $V_{CC}=2.7 \sim 5.5V$
- Output timing voltage : $V_{OL}=0.8V$, $V_{OH}=2.0V$
- Ports P1, P2 input : $V_{IL}=0.16V_{CC}$, $V_{IH}=0.5V_{CC}$

FLASH MEMORY CARDS

8/16-bit Data Bus

Flash Memory Card

MF84M1-G1EATXX

Connector Type

*Two-piece 68-pin***DESCRIPTION**

The MF84M1-G1EATXX is a flash memory card which uses sixteen two-megabit flash electrically erasable and programmable read only memory IC's.

DataSheet4U.com

DataSheet4U.com

FEATURES

- 68 pin JEIDA/PCMCIA
- 8 /16 controllable data bus width
- Buffered interface
- TTL interface level
- Program/erase operation by software command control
- Program/erase voltage 12V
- 10,000 program/erase cycles
- Write protect switch

APPLICATIONS

- Note book computers ■ Printers
- Industrial machines

PRODUCT LIST

Item Type name	Memory capacity	Data bus width (bits)	Access time (ns)	Connector type	Number of pins	Outline drawing
MF84M1-G1EATXX	4 MB	8 /16	250	Two-piece	68	68P-002

et4U.com

DataSheet4U.com

www.DataSheet4U.com

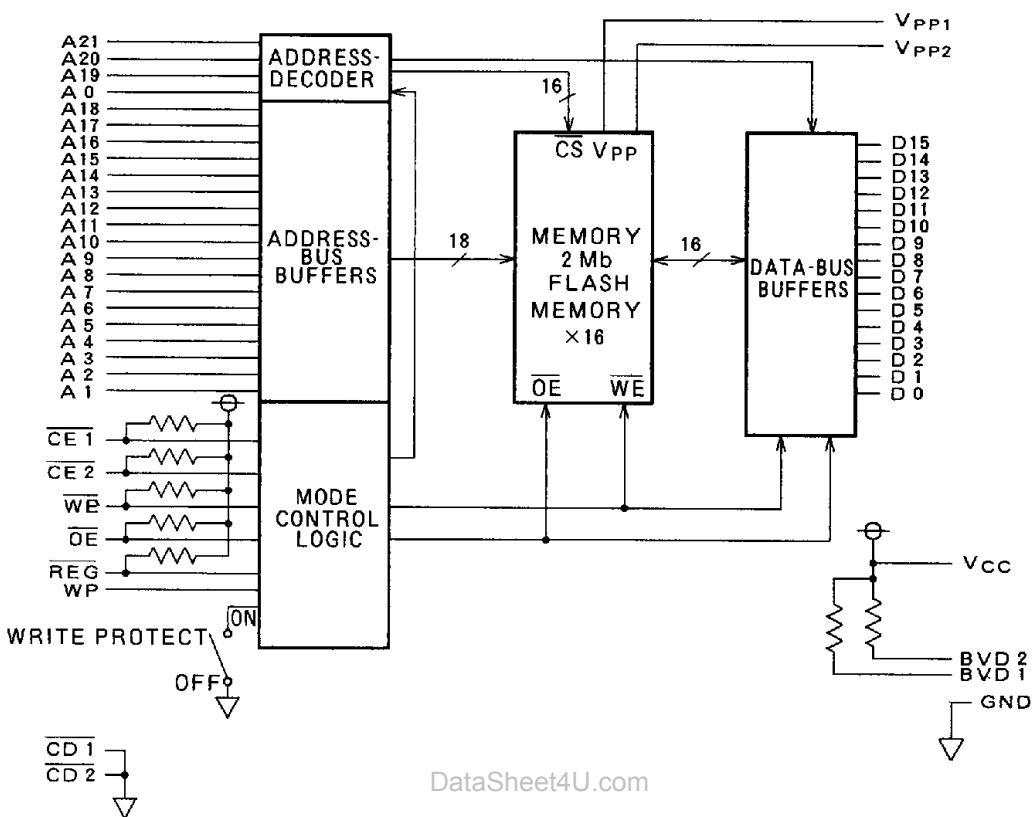
FLASH MEMORY CARDS

PIN ASSIGNMENT

Pin No	Symbol	Function	Pin No	Symbol	Function
1	GND	Ground	35	GND	Ground
2	D 3		36	CD 1	Card detect 1
3	D 4		37	D11	
4	D 5		38	D12	
5	D 6		39	D13	
6	D 7		40	D14	
7	CE 1	Card enable 1	41	D15	
8	A10	Address input	42	CE 2	Card enable 2
9	OE	Output enable	43	NC	
10	A11		44	NC	
11	A 9		45	NC	
12	A 8		46	A17	
13	A13		47	A18	
14	A14		48	A19	
15	WE	Write enable	49	A20	
16	NC	No connection	50	A21	
17	Vcc	Power supply voltage	51	VCC	Power supply voltage
18	VPP 1	Programming supply voltage 1	52	VPP 2	Programming supply voltage 2
19	A16		53	NC	
20	A15		54	NC	
21	A12		55	NC	
22	A 7		56	NC	
23	A 6		57	NC	
24	A 5		58	NC	
25	A 4		59	NC	
26	A 3		60	NC	
27	A 2		61	REG	Attribute memory select
28	A 1		62	BVD 2	Battery voltage detect 2
29	A 0		63	BVD 1	Battery voltage detect 1
30	D 0		64	D 8	
31	D 1		65	D 9	
32	D 2		66	D10	
33	WP	Write protect	67	CD 2	Card detect 2
34	GND	Ground	68	GND	Ground

FLASH MEMORY CARDS

BLOCK DIAGRAM (MF84M1-G1 EATXX)



DataSheet4U.com

FUNCTIONAL DESCRIPTION

The operating mode of the card is determined by five active low control signals (REG, CE1, CE2, OE, WE), three supply voltages (V_{CC}, V_{PP1}, V_{PP2}) and control registers located in each memory IC.

Common memory function

When the REG signal is set to a high level common memory is selected.

Read only mode

When the voltages applied to both V_{PP1} and V_{PP2} are less than the voltage applied to V_{CC} (i.e. V_{PP} = 0V to V_{CC}), the control registers of each memory IC are set to read only mode.

Operation of the card then depends on the four possible combinations of CE1 and CE2 (note/WE should be set to a high level when the device is in read only mode except during combination (4) where it's condition is unimportant) :

(1) If CE1 is set to a low level and CE2 is set to a high level, the card will work as an eight bit data bus width card. Data can be accessed via the lower

half of the data bus (D0 to D7).

(2) If both CE1 and CE2 are set to a low level, data will be accessible via the full sixteen bit data bus width of the card. In this mode LSB of address bus (A0) is ignored.

(3) If CE1 is set to a high level and CE2 is set to a low level the odd bytes (only) can be accessed through upper half of the data bus (D8 to D15). This mode is useful when handling the odd (upper) bytes in a sixteen bit interface system. Note that A0 is also ignored in this operating condition.

(4) If CE1 and CE2 are set to a high level, the card will be in standby mode where it consumes low power. The data bus is kept high impedance.

When OE is set to a low level data can be read from the card, depending on the address applied and the setting of CE1 and CE2 as mentioned above, except under combination (4).

www.DataSheet4U.com

FLASH MEMORY CARDS

When OE is set to a high level and WE is set to a high level the card is in an output disable mode and the data bus will be in a high impedance state regardless of the condition of CE1 and CE2.

Read/write mode

When a programming voltage (V_{PPH}) is applied to either or both of V_{PP1} and V_{PP2}, read/write mode is enabled for the corresponding banks of memory IC's inside the card. V_{PP1} enables the Even Byte bank and V_{PP2} enables the Odd Byte bank.

By using the 4 combinations of CE1 and CE2 as described under Read only mode above the appropriate Data Out and Command/Data In bus selection can be made.

If OE is set to a high level and WE set to a low level, the control register will latch command data applied at the rising edge of the WE signal. Note that more than one bus cycle may be required to latch the command and/or the related data – please refer to the Command Definition table.

If OE is set to a low level and WE is set to a high level the card data can be read from the card depending on the condition of the control register.

After latching the command data, the card will go into programming, erasure or other operation mode. For details please refer to the Command Definition table, each individual command's definition and the programming and erasure algorithms.

Attribute memory

When REG is set to a low level attribute memory is selected.

The card then outputs FFh on the lower half of the data bus (D0 to D7) when the following conditions are applied :

- (1) CE1 : low level, CE2 : high level, OE : low level, WE : high level, A0 : low level
- (2) CE1 : low level, CE2 : low level, OE : low level, WE : high level.

Write protect mode

The card has a write protect switch on the opposite edge to the connector edge. When it is switched on, the card will be placed into a write protect mode, where data can be read from the card but it cannot be written to it. The WP output pin is set to a high level when the card is in write protect mode and Vcc is applied. When the card is not in write protect mode the WP output pin is set to a low level when Vcc is applied. By reading the state of the WP output the host system can easily check whether the card is in write protect mode or not.